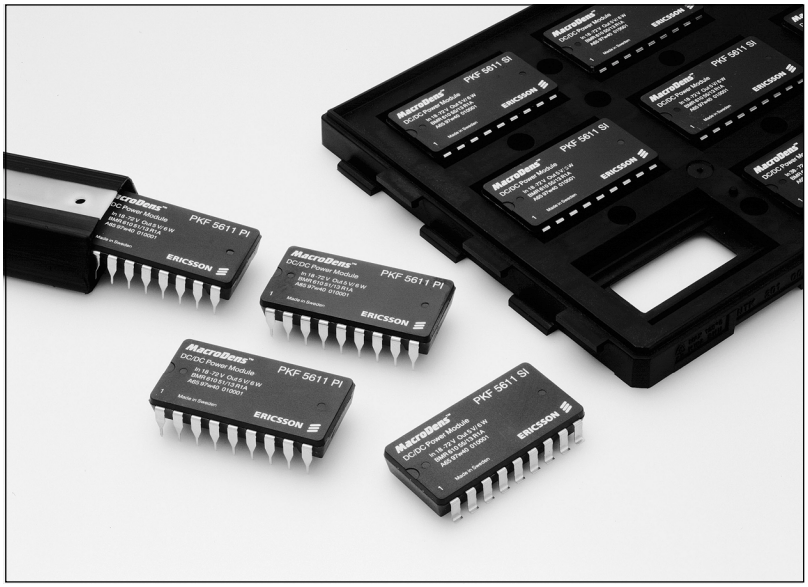
5–6 W DC/DC Power Modules
Wide Input Series

- *SMD and through-hole versions with ultra low component height 8 mm (0.315 in.)*
- *18–72 V input voltage range*
- *82% efficiency (typ at 5 V)*
- *1,500 V dc isolation voltage*
- *Switching frequency syncronization*
- *MTBF >4.9 million hours at +55°C case temperature (+40 °C ambient)*
- *Low EMI measured according to CISPR 22 and FCC part 15J*



Patents
US: D357901 DE: M94022763

The MacroDens™ PKF 5000 I series true component level on-board DC/DC power modules are intended as distributed power sources in decentralized 24, 48 and 60 V DC power systems. Utilization of thick film technology and a high degree of silicon integration has made it possible to achieve a MTBF of more than 4.9 million hour.

The highly reliable and rugged over-moulded design and the ultra low height of these DC/DC power modules makes them particularly suited for Information Technology and Telecom (IT&T) and other demanding industrial applications, with board spacing down to 15 mm or 0.6 in. These DC/DC power modules are optimized for free convection cooling and have an operational ambient temperature range in compliance with present and future application needs, including non temperature controlled environments.

The mechanical design offers the choice of surface mount or through-hole versions, delivered in ready-to-use tubes, trays or tape & reel package, and compatibility with semi and fully aqueous cleaning processes.

The PKF series is manufactured using highly automated manufacturing lines with a world-class quality commitment and a five-year warranty. Ericsson Microelectronics AB has been an ISO 9001 certified supplier since 1991. *For a complete product program please reference the back cover.*

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General

Absolute Maximum Ratings

Characteristics		min	max	Unit
T_C	Case temperature at full output power	–45	+100	°C
T_S	Storage temperature	–55	+125	°C
V_I	Continuous input voltage[1)]	–0.5	+75	Vdc
V_{ISO}	Isolation voltage (input to output test voltage)	1,500		Vdc
W_{tr}	Transient input energy		0.01	Ws
V_{RC}	Remote control voltage pin 10,11	–5	+16	Vdc
V_{adj}	Output adjust voltage pin 8, 9	–5	+40	Vdc

Stress in excess of Absolute Maximum Ratings may cause permanent damage. Absolute Maximum Ratings, sometimes referred to as no destruction limits, are normally tested with one parameter at a time exceeding the limits of Output data or Electrical Characteristics. If exposed to stress above these limits, function and performance may degrade in an unspecified manner.

Input $T_C < T_{Cmax}$ unless otherwise specified

Characteristics		Conditions	min	typ	max	Unit
V_I	Input voltage range[1)]		18		72	V
V_{Ioff}	Turn-off input voltage	(See typical characteristics)	15	16		V
V_{Ion}	Turn-on input voltage	(See typical characteristics)		17.4	17.9	V
C_I	Input capacitance			1.4		µF
P_{Ii}	Input idling power	$I_O = 0, T_C = -30…+90$ °C	(V_I = 27V) (V_I = 53V)	244 240		mW
P_{RC}	Input stand-by power	$T_C = -30…+90$ °C RC connected to pin 17	(V_I = 27V) (V_I = 53V)	18 67		mW

NOTES:

1) The input voltage range 18…72 Vdc meets the European Telecom Standard ETS 300 132-2 Nominal input voltage range in 48 V and 60 Vdc power systems, –40.5… –57.0 V and –50.0…–72.0 V respectively. At input voltages exceeding 72 V (abnormal voltage) the power loss will be higher than at normal input voltage and T_C must be limited to max +90 °C. Absolute max continuous input voltage is 75 Vdc. Output characteristics will be marginally affected at input voltages exceeding 72 V.

2) The test is applicable for through-hole versions.

Environmental Characteristics

Characteristics	Test procedure & conditions		
Vibration (Sinusoidal)	JESD 22-B103 (IEC 68-2-6 F_c)	Frequency Amplitude Acceleration Number of cycles	10…500 Hz 0.75 mm 10 g 10 in each axis
Random vibration	MIL-STD-883 Method 2026 (IEC 68-2-34 E_d)	Frequency Acceleration density spectrum Duration Reproducability	10…500 Hz 0.5 g^2/Hz 10 min in 3 directions medium (IEC 62-2-36)
Shock (Half sinus)	JESD 22-B104 (IEC 68-2-27 E_a)	Peak acceleration Shock duration	200 g 3 ms
Temperature change	JESD 22-A104 (IEC 68-2-14 N_a)	Temperature Number of cycles	–40°C…+125°C 500
Accelerated damp heat	JESD 22-A101 (IEC 68-2-3 C_a with bias)	Temperature Humidity Duration	85°C 85% RH 1000 hours
Solder resistability[2)]	JESD 22-B106 (IEC 68-2-20 T_b 1A)	Temperature, solder Duration	260°C 10…13 s
Aggressive environment	IEC 68-2-11 K_a	Duration Temperature Concentration	96 h 35°C 5 %

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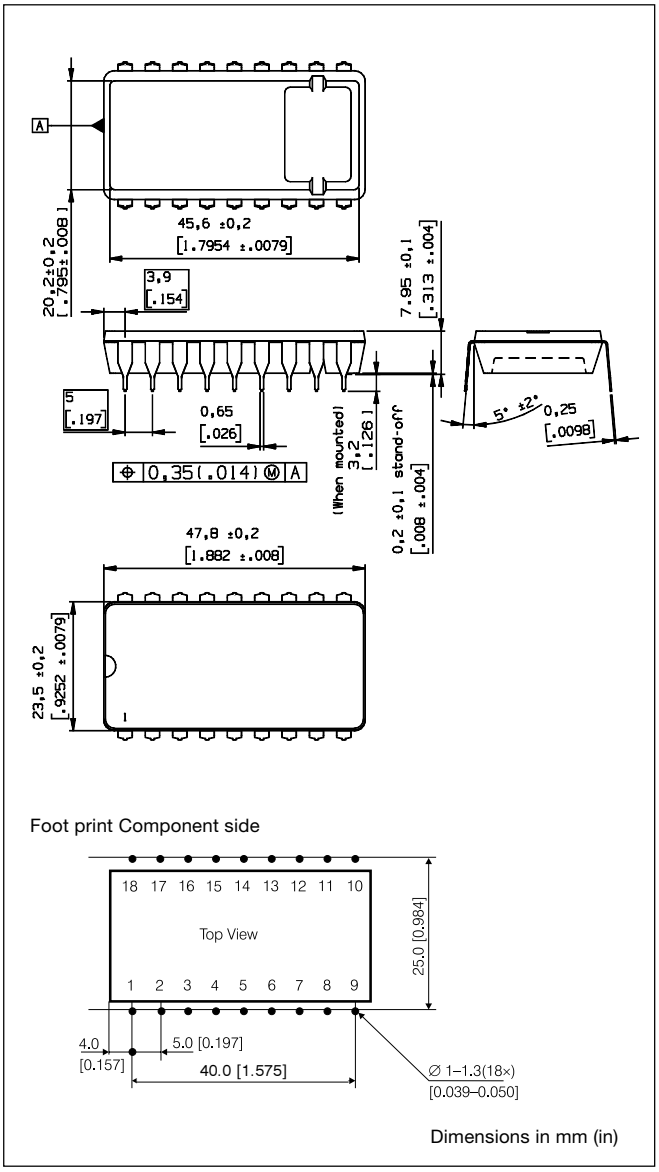
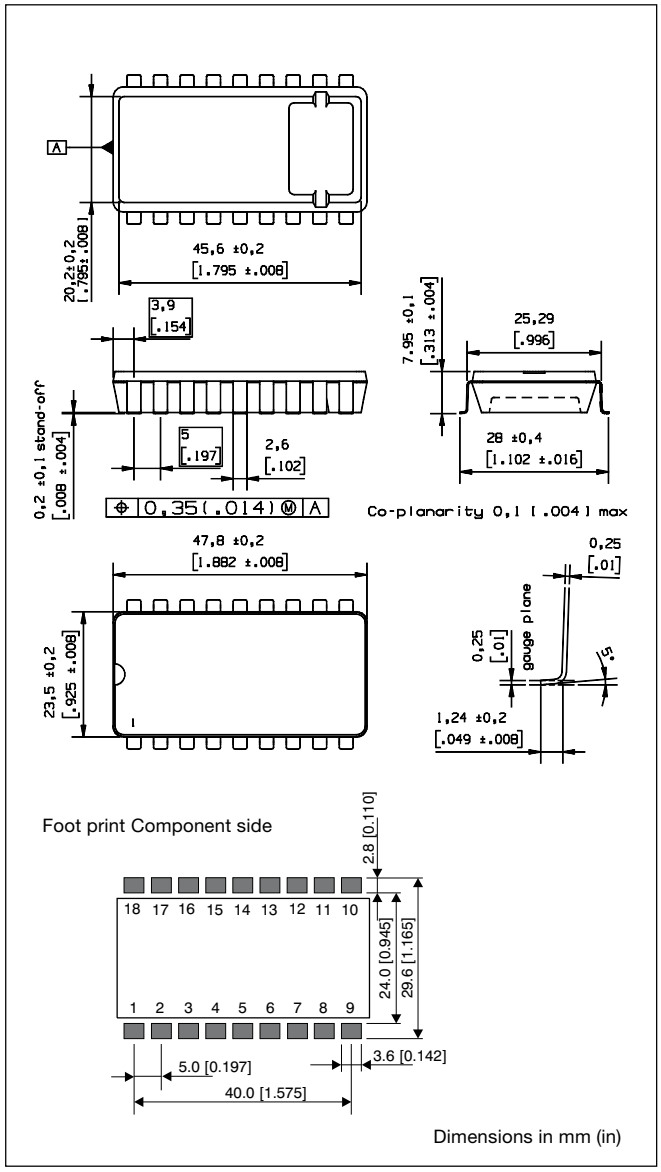
Mechanical Data

Through-hole version



Surface-mount version



Connections

Pin	Designation	Function
1	Out 1	Output 1. Positive voltage ref. to Rtn.
2	Rtn	Output return.
3–6	NC	Not connected.
7	Sync	Synchronization input.
8	V_{adj}	Output voltage adjust. To set typical output voltage (V_{Oi}) connect pin 8 to pin 9.
9	NOR	Connection of Nominal Output voltage Resistor. (See output voltage adjust p. 12).
10	Aux	Internally connected to pin 11.
11	RC	Remote control and turn-on/off input voltage adjust. Used to turn-on and turn-off output.
12–16	NC	Not connected.
17	–In	Negative input.
18	+In	Positive input.

Weight

Maximum 20 g (0.71 oz).

Case

The case consists of semiconductor grade epoxy with embedded pins.

Coefficient of thermal expansion (CTE) is typ. 15 ppm/°C.

Connection Pins

Base material is copper (Cu), first plating is nickel (Ni) and second (outer) plating is palladium (Pd).

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Thermal Data

Over-temperature protection

The PKF 5000 series will automatically shut down when the internal junction temperature of the control IC in the converter reaches typ. 150 °C.
It will automatically re-start when the junction temperature cools below typ. 140 °C.

Two-parameter model

This model provides a more precise description of the thermal characteristics to be used for thermal calculations.

Thermally the power module can be considered as a component and the case temperature can be used to characterize the properties. The thermal data for a power module with the substrate in contact with the case can be described with two thermal resistances. One from the case to ambient air and one from case to PB (Printed Board).

The thermal characteristics can be calculated from the following formula:

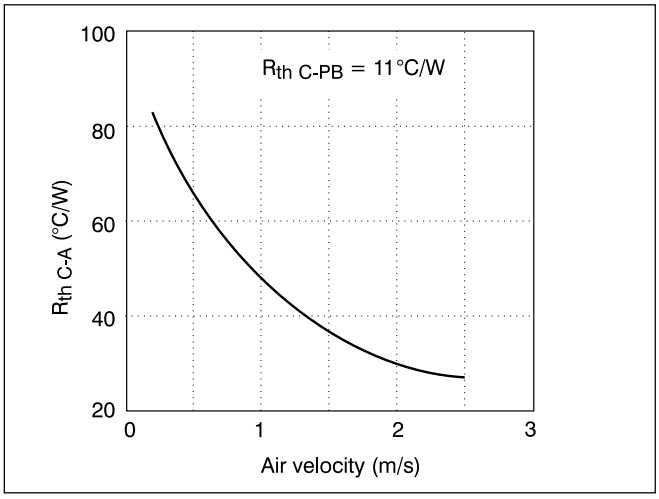
$$T_{PB} = (T_C - T_A) \times (R_{th\ C-PB} + R_{th\ C-A}) / R_{th\ C-A} - P_d \times R_{th\ C-PB} + T_A$$

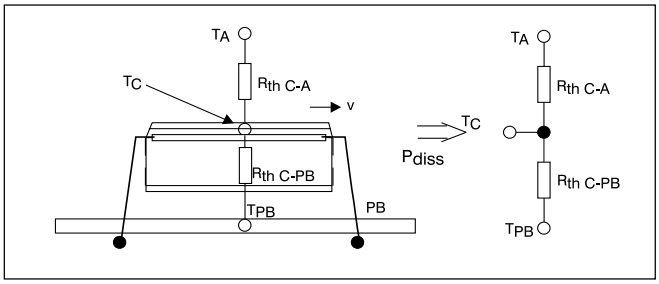
Where:

P_d:	dissipated power, calculated as $P_O \times (1/\eta - 1)$
T_C:	max average case temperature
T_A:	ambient air temperature at the lower side of the power module
T_{PB}:	temperature in the PB between the PKF connection pins
$R_{th\ C-PB}$:	thermal resistance from case to PB under the power module
$R_{th\ C-A}$:	thermal resistance from case to ambient air
v:	velocity of ambient air.

$R_{th\ C-PB}$ is constant and $R_{th\ C-A}$ is dependent on the air velocity.

Free convection is equal to an air velocity of approx. 0.2 – 0.3 m/s. See figure below.





Reflow Soldering Information

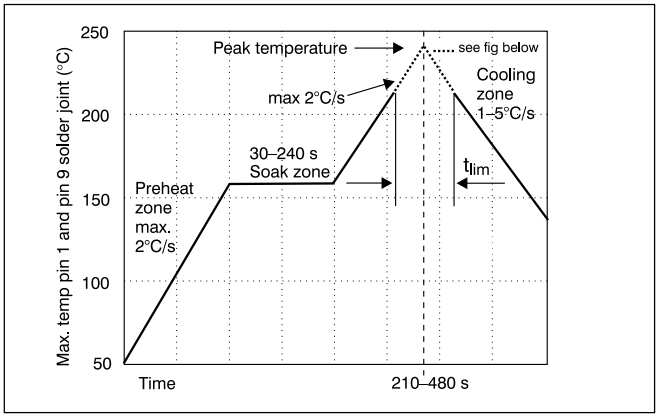
The PKF series of DC/DC power modules are manufactured in surface mount technology. Extra precautions must therefore be taken when reflow soldering the surface mount version. Neglecting the soldering information given below may result in permanent damage or significant degradation of power module performance.

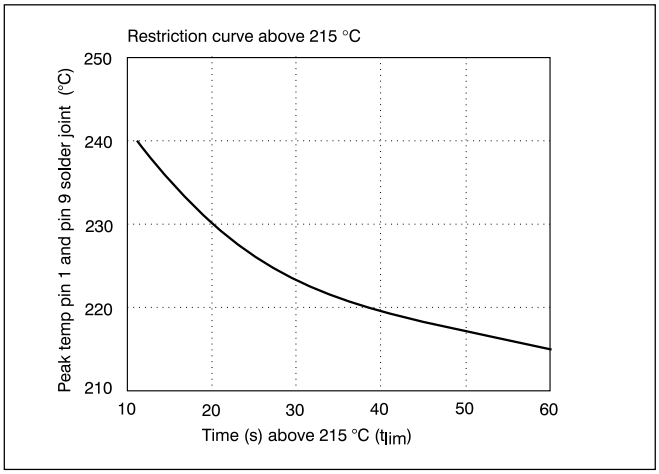
The PKF series can be reflow soldered using IR, Natural Convection, Forced Convection or Combined IR/Convection Technologies. The high thermal mass of the component and its effect on ΔT (°C) requires that particular attention be paid to other temperature sensitive components.

IR Reflow technology may require the overall profile time to be extended to approximately 8–10 minutes to ensure an acceptable ΔT. Higher activity flux may be more suitable to overcome the increase in oxidation and to avoid flux burn-up.

The general profile parameters detailed in the diagram, with this extended time to reach peak temperatures, would then be suitable.

Note! These are maximum parameters. Depending on process variations, an appropriate margin must be added.





Palladium plating is used on the terminal pins. A pin temperature (T_p) in excess of the solder fusing temperature (+183°C for Sn/Pb 63/37) for more than 25 seconds and a peak temperature above 195°C, is required to guarantee a reliable solder joint.

Both pin 1 and pin 9 must be monitored.

No responsibility is assumed if these recommendations are not strictly followed.

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Safety

The PKF Series DC/DC power modules are designed in accordance with EN 60 950, *Safety of information technology equipment including electrical business equipment*. SEMKO approval pending.

The DC/DC power module shall be installed in an end-use equipment and considerations should be given to measuring the case temperature to comply with $T_{C\,max}$ when in operation. Abnormal component tests are conducted with the input protected by an external 3 A fuse. The need for repeating these tests in the end-use appliance shall be considered if installed in a circuit having higher rated devices.

When the supply to the DC/DC power module meets all the requirements for SELV (<60 V dc), the output is considered to remain within SELV limits (level 3). The isolation is an operational insulation in accordance with EN 60 950.

The DC/DC power module is intended to be supplied by isolated secondary circuitry and shall be installed in compliance with the requirements of the ultimate application. If they are connected to a 60 V DC system reinforced insulation must be provided in the power supply that isolates the input from the mains. Single fault testing in the power supply must be performed in combination with the DC/DC power module to demonstrate that the output meets the requirement for SELV. One pole of the input and one pole of the output is to be grounded or both are to be kept floating.

The terminal pins are only intended for connection to mating connectors of internal wiring inside the end-use equipment.

These DC/DC power modules may be used in telephone equipment in accordance with paragraph 34 A.1 of UL 1459 (Standard for Telephone Equipment, second edition).

The galvanic isolation is verified in an electric strength test. Test voltage (V_{ISO}) between input and output is 1,500 V dc for 60 s. In production the test duration is decreased to 1 s.

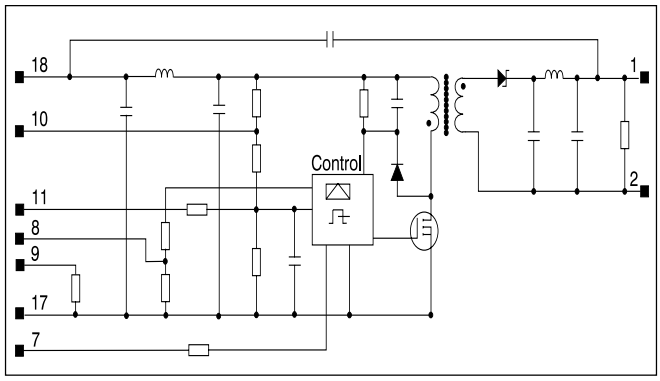
The capacitor between input and output has a value of 1 nF and the leakage current is less than 1µA @ 53 V dc.

The case is designed in non-conductive epoxy. Its flammability rating meets UL 94V-0. The oxygen index is 34%.

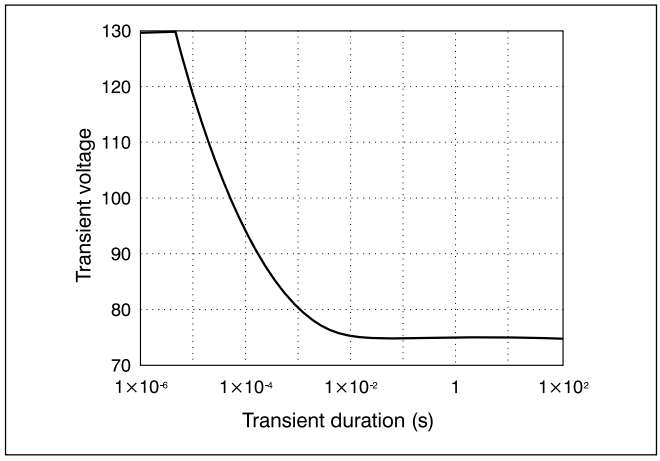
Electrical Data

Fundamental circuit diagrams

Single output



Transient input voltage



Single voltage pulse at +25 °C ambient temperature.

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PKF 5510 PI, SI

T_C = –30…+90°C, V_I = 18 ...72V and pin 8 connected to pin 9 unless otherwise specified.

Output

Characteristics		Conditions		Output 1 min	Output 1 typ	Output 1 max	Unit
V_{Oi}	Output voltage initial setting and accuracy	T_C = +25°C, I_O = 1.5 A, V_I = 53 V		3.27	3.30	3.33	V
	Output adjust range[1]			2.80		3.80	V
V_O	Output voltage tolerance band	Long term drift incl.	I_O = 0.15…1.5 A	3.00		3.46	V
			I_O = 0.15…1.5 A, V_I = 19–72 V	3.13		3.46	
			I_O = 0.2…1.5 A, V_I = 20-72 V	3.17		3.42	
	Idling voltage	I_O = 0 A			3.8	4.3	V
	Line regulation	I_O = 1,5 A	V_I = 18…36 V		30		mV
			V_I = 38…60 V		30		
			V_I = 50…72 V		15		
	Load regulation	I_O = 0.15…1.5 A, V_I = 53 V		50		200	mV
t_{tr}	Load transient recovery time	I_O = 0.15…1.5 A, V_I = 53 V load step = 0.75 A			100		µs
V_{tr}	Load transient voltage				+150		mV
					–150		mV
T_{coeff}	Temperature coefficient[2]	I_O =1.5 A, T_C = +40…+90 °C			–0.4		mV/°C
t_r	Ramp-up time	I_O = 1.5 A, 0.15…1.5 ×V_O			2		ms
t_s	Start-up time	I_O = 0.15…1.5A, V_I = 53 V From V_I connection to V_O = 0…0.9×V_{Oi}			5		ms
I_O	Output current			0		1.5	A
P_{Omax}	Max output power[2]	Calculated value		5			W
I_{lim}	Current limiting threshold	T_C <T_{Cmax}, V_O = 3.0 V		1.65	2.30	2.50	A
I_{sc}	Short circuit current	V_O = 0.2…0.5 V, T_A = +25 °C			2.7		A
V_{Oac}	Output ripple & noise	I_O = 1.5 A	20 Hz…5 MHz		20	70	mV_{p-p}
			0.6 …50 MHz			80	dBµV
SVR	Supply voltage rejection (ac)	f = 100 Hz sine wave, 1V_{p-p}, V_I = 53 V (SVR = 20 log (1 V_{p-p}/V_{Op-p}))			45		dB

[1] See also Operating Information.
[2] See Typical Characteristics.

Miscellaneous

Characteristics		Conditions		min	typ	max	Unit
η	Efficiency	I_O = 1.5 A	V_I = 27 V	78	80		%
			V_I = 53 V	75	78		
P_d	Power dissipation		V_I = 27 V		1.2	1.4	W
			V_I = 53 V		1.4	1.7	

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PKF 5611 PI, SI

T_C = –30…+90°C, V_I = 18 ...72V and pin 8 connected to pin 9 unless otherwise specified.

Output

Characteristics		Conditions		Output 1 min	Output 1 typ	Output 1 max	Unit
V_{Oi}	Output voltage initial setting and accuracy	T_C = +25°C, I_O = 0.2 A, V_I = 53 V		5.02	5.05	5.08	V
	Output adjust range[1]			4.30		5.80	V
V_O	Output voltage tolerance band	Long term drift included	I_O = 0.15…1.2 A	4.85		5.25	V
	Idling voltage	I_O = 0 A			5.7	6.0	V
	Line regulation	I_O = 1.2 A	V_I = 18…36 V		50		mV
			V_I = 38…60 V		20		
			V_I = 50…72 V		10		
	Load regulation	I_O = 0.3…1.2 A, V_I = 27 V			135		mV
t_{tr}	Load transient recovery time	I_O = 0.12…12 A, V_I = 53 V load step = 0.6 A			330		µs
V_{tr}	Load transient voltage				+120		mV
					–120		mV
T_{coeff}	Temperature coefficient[2]	I_O = 1.2 A, T_C =+40…+90°C			–1.1		mV/°C
t_r	Ramp-up time	I_O = 1.2 A, 0.1…0.9 ×V_O		1	2	5	ms
t_s	Start-up time	I_O = 0.1…1.2 A, V_I = 53 V From V_I connection to V_O = 0…0.9 ×V_{Oi}			4.8	10	ms
I_O	Output current			0		1.2	A
P_{Omax}	Max output power[2]	Calculated value		6			W
I_{lim}	Current limiting threshold	T_C <T_{Cmax}, V_O = 4.0 V		1.3	1.8	2.0	A
I_{sc}	Short circuit current	V_O = 0.2…0.5 V, T_A =+25 °C			2.0	3.5	A
V_{Oac}	Output ripple & noise	I_O = 1.2 A	20 Hz…5 MHz		50	150	mV_{p-p}
			0.6 …50 MHz			80	dBµV
SVR	Supply voltage rejection (ac)	f = 100 Hz sine wave, 1V_{p-p}, V_I = 53 V (SVR = 20 log (1 V_{p-p}/V_{Op-p}))			60		dB

[1] See also Operating Information.
[2] See Typical Characteristics.

Miscellaneous

Characteristics		Conditions		min	typ	max	Unit
η	Efficiency	I_O = 1.2 A	V_I = 27 V	79	83		%
			V_I = 53 V	79	81		
P_d	Power dissipation		V_I = 27 V		1.2	1.6	W
			V_I = 53 V		1.4	1.6	

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PKF 5617 PI, SI

T_C = –30…+90°C, V_I = 18 ...72 V and pin 8 connected to pin 9 unless otherwise specified.

Output

Characteristics		Conditions		Output 1 min	Output 1 typ	Output 1 max	Unit
V_{Oi}	Output voltage initial setting and accuracy	T_C = +25°C, I_O = 0.72 A, V_I = 53 V		6.95	7.00	7.05	V
	Output adjust range[1)]			5.95		8.05	V
V_O	Output voltage tolerance band	Long term drift included	I_O = 0.086…0.86 A	6.65		7.35	V
	Idling voltage	I_O = 0 A, V_I =53 V			7.5	7.9	V
	Line regulation	I_O =0.86 A	V_I = 18…36 V		10		mV
			V_I = 38…60 V		10		
			V_I = 50…72 V		10		
	Load regulation	I_O = 0.08…0.86 A, V_I = 27 V			120		mV
t_{tr}	Load transient recovery time	I_O = 0.086…0.86 A, V_I = 53 V load step = 0.43 A			350		µs
V_{tr}	Load transient voltage				+130		mV
					–130		mV
T_{coeff}	Temperature coefficient[2)]	I_O = 0.86 A, T_C = +40…+90°C			–1.2		mV/°C
t_r	Ramp-up time	I_O = I_{Omax}, 0.1…0.9 ×V_O, V_I = 53 V		1	3	5	ms
t_s	Start-up time	I_O = 0.086…0.86 A, V_I = 53 V From V_I connection to V_O = 0.9 ×V_{Oi}			5	10	ms
I_O	Output current			0		0.86	A
P_{Omax}	Max output power[2)]	Calculated value		6			W
I_{lim}	Current limiting threshold	T_C <T_{Cmax}, V_O = 4.0 V		1.0	1.2	1.6	A
I_{sc}	Short circuit current	V_O = 0.2…0.5 V, T_A = +25°C			1.8	3.5	A
V_{Oac}	Output ripple & noise	I_O =0.86 A	20 Hz…5 MHz		50	150	mV_{p-p}
			0.6 …50 MHz			80	dBµV
SVR	Supply voltage rejection (ac)	f = 100 Hz sine wave, 1V_{p-p}, V_I = 53 V (SVR = 20 log (1 V_{p-p}/V_{Op-p}))			60		dB

[*1)] See also Operating Information.
[12)] See Typical Characteristics.

Miscellaneous

Characteristics		Conditions		min	typ	max	Unit
η	Efficiency	I_O = 0.86 A	V_I = 27 V	80	84		%
			V_I = 53 V	80	82		
P_d	Power dissipation		V_I = 27 V		1.1	1.5	W
			V_I = 53 V		1.3	1.5	

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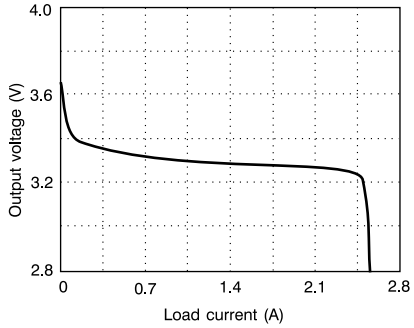
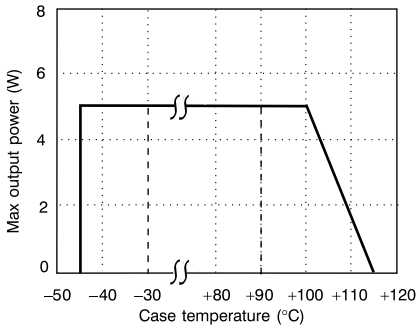
Typical Characteristics

PKF 5510 PI, SI

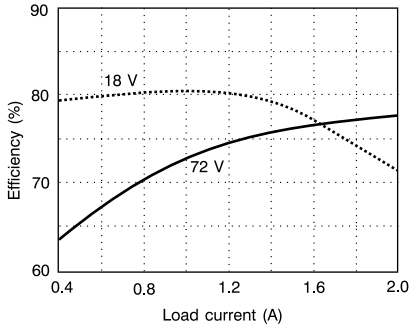
Output characteristic (typ)



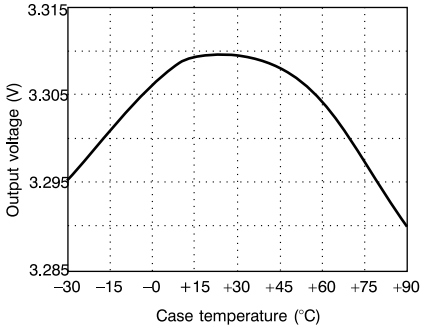
Power derating



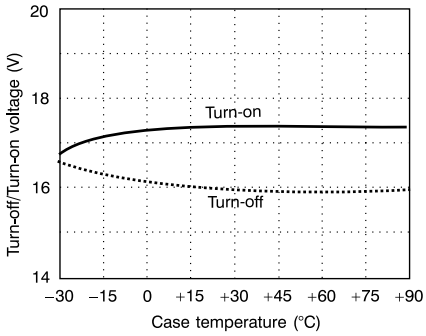
Efficiency (typ) @ T_A = +25°C



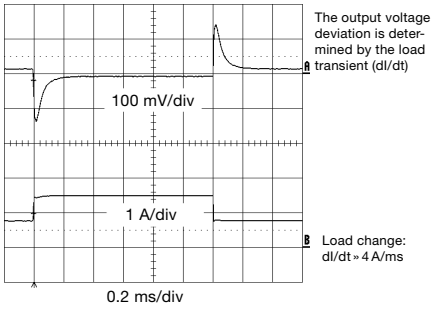
Temperature coefficient



Turn-on/turn/off input voltage

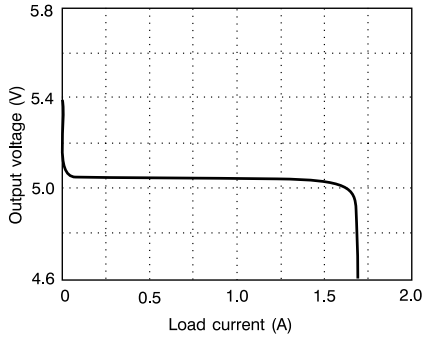


Dynamic load response (typ)@+25C

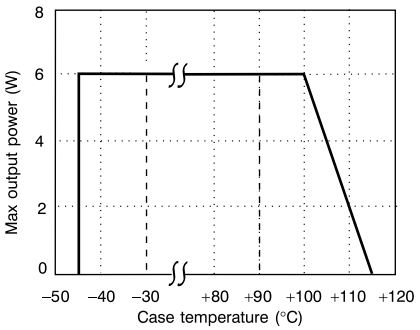


PKF 5611 PI, SI

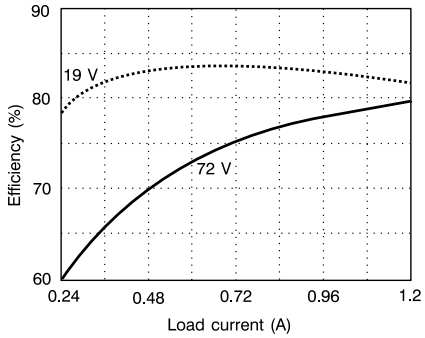
Output characteristic (typ)



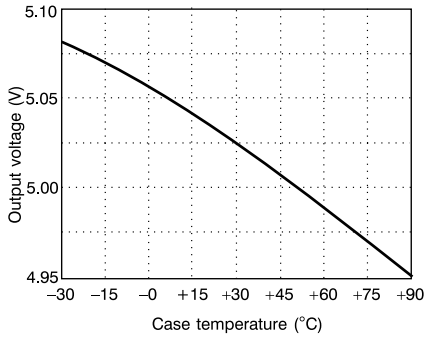
Power derating



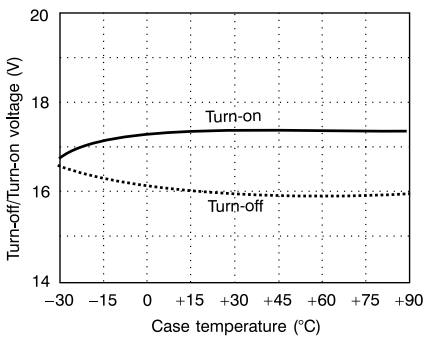
Efficiency (typ) @ T_A = +25°C



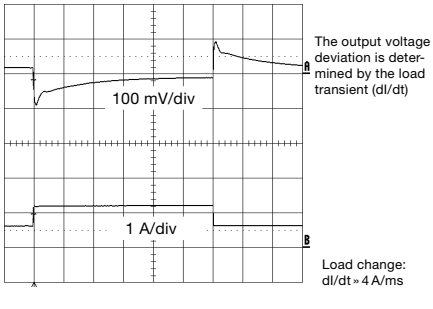
Temperature coefficient



Turn-on/turn/off input voltage



Dynamic load response (typ)@+25C



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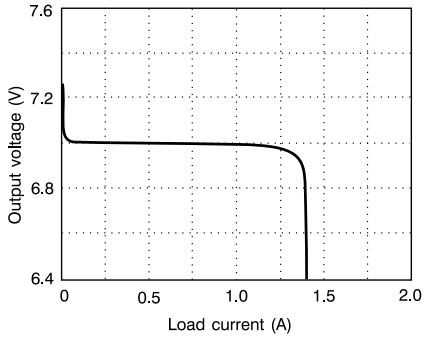
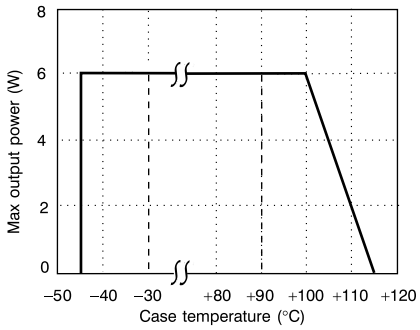
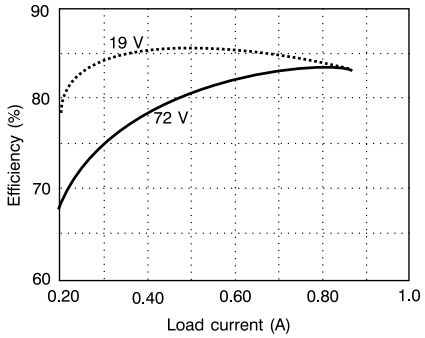
Output characteristic (typ)



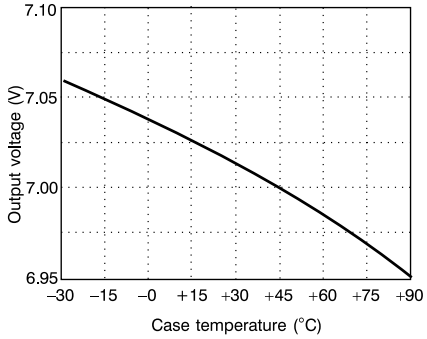
Power derating



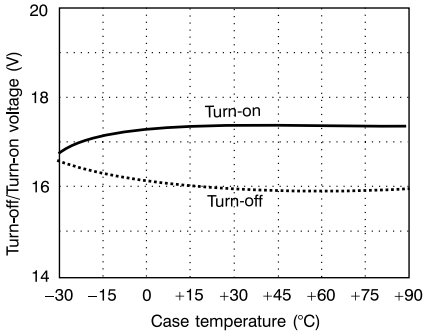
Efficiency (typ) @ T_A = +25°C



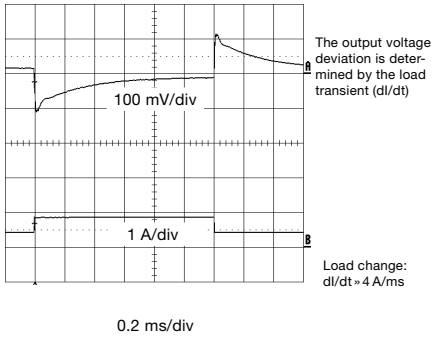
Temperature coefficient



Turn-on/turn/off input voltage



Dynamic load response (typ) @ + 25C



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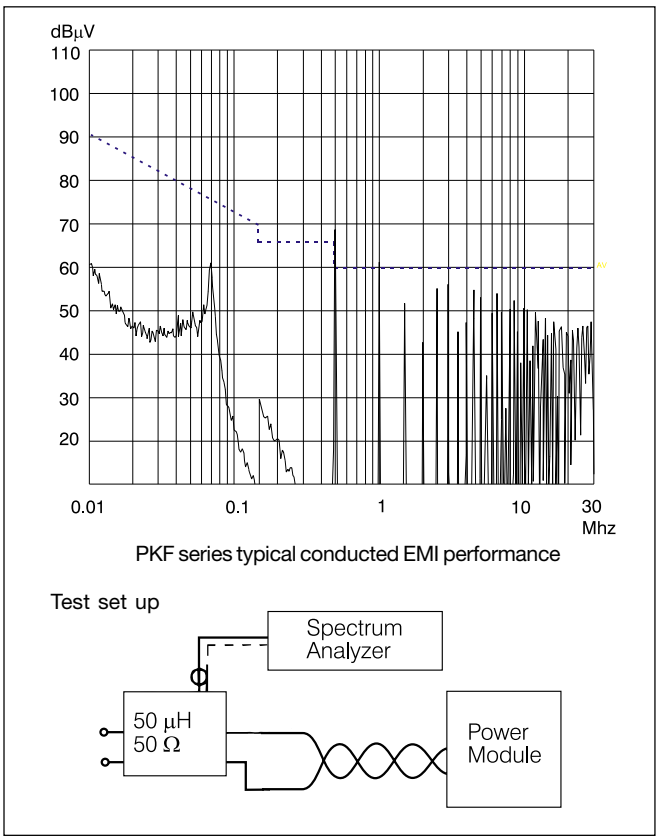
EMC Specifications

The fundamental switching frequency is 510 kHz ± 26 kHz.

Conducted EMI (input teminals)



The PKF meets class A in VDE 0871/0878, FCC Part 15J, and CISPR 22 (EN 55022), except for the fundamental switching frequency.

Conducted EMS

Electro Magnetic Susceptibility is measured by injection of electrical disturbances on the input terminals. No deviation outside the V_O tolerance band will occur under the following conditions:

Frequency range	Voltage level
0.15...300 MHz	1.0 V_{rms}

The signal is amplitude modulated with 1 kHz/80% and applied both differential and common mode.

Radiated EMS (Electro-Magnetic Fields)

Radiated EMS is measured according to test methods in IEC Standard publ. 801-3. No deviation outside the V_O tolerance band will occur under the following conditions:

Frequency range	Voltage level
0.01...200 MHz	3 V_{rms}/m
200...1,000 MHz	3 V_{rms}/m
1...12 GHz	10 V_{rms}/m

ESD

Electro Static Discharge is tested according to IEC publ. 801-2. No destruction will occur if the following voltage levels are applied to any of the terminal pins:

Test	Voltage level
Air discharge	±4 kV
Contact discharge	±2 kV

EFT

Electrical Fast Transients on the input terminals could affect the output voltage regulation causing functional errors on the Printed Board Assembly (PBA). The PKF power modules withstand EFT levels of 0.5 kV keeping V_O within the tolerance band and 2.0 kV without destruction. Tested according to IEC publ. 801-4.

Output Ripple & Noise ($V_O$ac)

Output ripple is measured as the peak to peak voltage of the fundamental switching frequency.

Operating Information

Fuse Considerations

To prevent excessive current from flowing through the input supply line, in the case of a short-circuit across the converter input, an external fuse should be installed in the non-earthed input supply line. We recommend using a fuse rated at approximately 2 to 4 times the value calculated in the formula below:

$$I_{in\,max} = \frac{P_{O\,max}}{(\eta_{min} \times V_{I\,min})}$$

For further information, please refer to the fuse manufacturer .

Remote Control (RC)

Turn-on or turn-off can be realized by using the RC-pin. If pin 11 is connected to pin 17 the power module turns off. Normal operation is achieved if pin 11 is open (NC) . To ensure safe turn-off the voltage difference between pin 11 and 17 shall be less than 2.0 V. RC is an TTL open collector compatible output with a sink capacity >300 µA (see fig. 1).

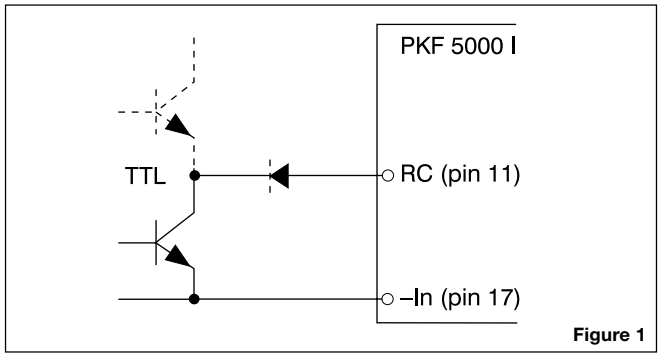


Figure 1

Over Voltage Protection (OVP)

The remote control can also be utilized for OVP by using the external circuitry in figure 2. Resistor values are for 5 V output applications, but can easily be adjusted for other output voltages and the desired OVP level.

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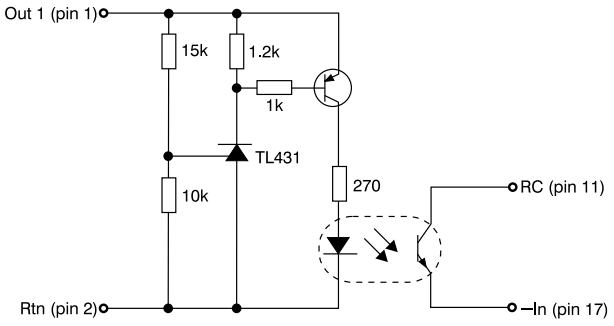

Figure 2

Output Voltage Adjust (V_{adj})

Output voltage, V_O, can be adjusted by using an external resistor. Typical adjust range is ± 15%. If pin 8 and 9 are not connected together the output will decrease to a low value.To increase V_O a resistor should be connected between pin 8/9 and 17, and to decrease V_O a resistor should be connected between pin 8 and 9 (see fig. 4).

Typical required resistor value to **increase V_O** is given by:

$R_{adj} = k_1 \times (k_2 - V_O)/(V_O - V_{Oi})$, (kΩ)

where V_O is the desired output voltage
V_{Oi} is the typical output voltage initial setting

and	k_1=3.18	k_2=3.86	PKF 5510
	k_1=3.18	k_2=5.93	PKF 5611
	k_1=3.18	k_2=8.05	PKF 5617

Typical required resistor value to **decrease V_O** is given by:

$R_{adj} = k_3 \times (V_{Oi} - V_O)/(V_O - k_4)$, (kΩ)

where	k_3=13.0	k_4=2.75	PKF 5510
	k_3=12.6	k_4=4.28	PKF 5611
	k_3=12.6	k_4=5.95	PKF 5617

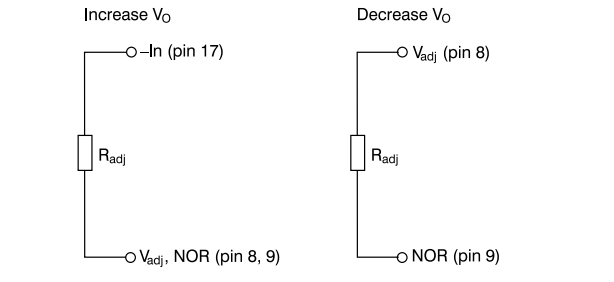

Figure 3

Voltage Margining

For voltage controlled margining e.g. at final test, the following setup can be used. By increasing the control voltage V1 to +10 V the output voltage decreases 5% of V_{Oi}, and by decreasing V1 to –10 V the output voltage increases 5%.

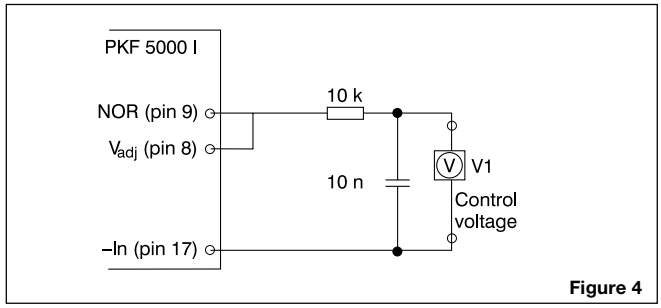

Figure 4

Capacitive Load

The PKF series has no maximum limit for capacitive load on the output. The power module may operate in current limiting mode during start-up, affecting the ramp-up and the start-up time. For optimum start performance we recommend maximum 100 µF/A of I_O. Connect capacitors at the point of load for best performance.

Parallel Operation

Paralleling of several converters is easily accomplished by direct connection of the output voltage terminal pins. The load regulation characteristic is specifically designed for optimal paralleling performance. Load sharing between converters will be within ±10%. It is recommended not to exceed $P_O = n \times 0.9 \times P_{Omax}$, where P_{Omax} is the maximum converter output power and n the number of paralleled converters, to prevent overloading any of the converters and thereby decreasing the reliability performance.

Current Limiting Protection (I_{lim})

The output power is limited at loads above the output current limiting threshold (I_{lim}), specified as a minimum value.

Synchronization (Sync)

It is possible to synchronize the switching frequency to an external symmetrical clock signal. The input is TTL-compatible and referenced to the input pin 17.

Characteristic	min	typ	max	unit
High level	2.2		6.5	V
Threshold level*)	1.2	1.7	2.2	V
Low level	0		0.4	V
Sink current			1.5	mA
Sync. frequency	520		688	kHz

*) Rise time <10ns

Input and Output Impedance

Both the source impedance of the power feeding and the load impedance will interact with the impedance of the DC/DC power module. It is most important to have the ratio between L and C as low as possible, i.e. a low characteristic impedance, both at the input and output, as the power modules have a low energy storage capability. Use an electrolytic capacitor across the input if the source is larger than 10 µH. Their equivalent series resistance together with the capacitance acts as a lossless damping filter. Suitable capacitor values are in the range 10–100 µF.

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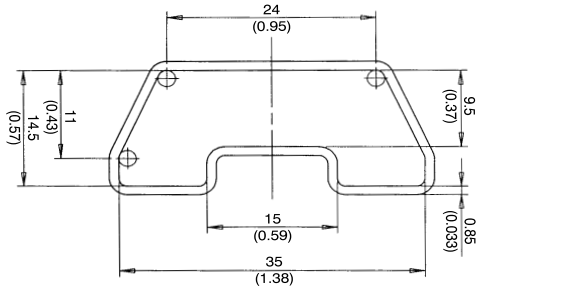
Delivery Package Information

Tubes

The PKF-series is delivered in tubes (designated by /A) with a length of 500 mm (19.69 in), see fig. 5.



All dimensions in mm (in)

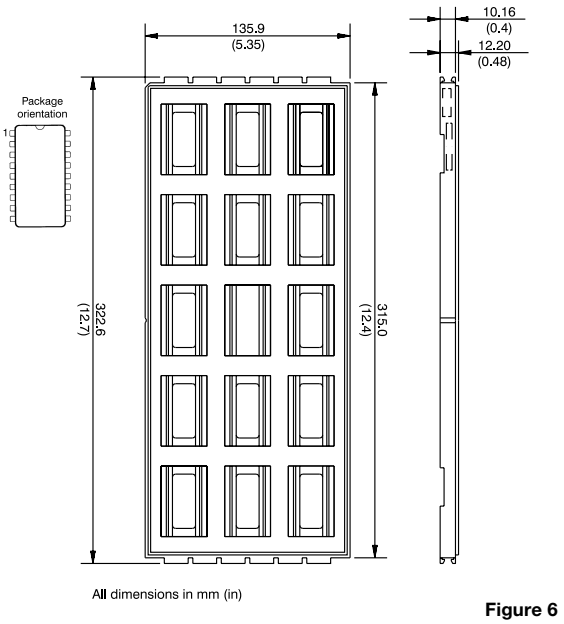
Figure 5

Specification

Material:	Antistatic coated PVC
Max surface resistance:	$10^{11}\Omega/\square$
Color:	Transparent
Capacity:	10 power modules/tube
Weight:	Typ. 60 g
End stops:	Pins

Trays

SMD versions, SI, can be delivered in standard JEDEC trays (designated by /B) on request, see fig. 6. For more information, please contact your local Ericsson sales office.



All dimensions in mm (in)

Figure 6

Specification

Material:	Polypropylene (PP)
Max temperature:	125 °C
Max surface resistance:	$10^{5}\Omega/\square$
Color:	Black
Capacity:	15 power modules/tray
Stacking pitch:	10.16 mm
Weight:	Typ. 130 g
Min. order quantity:	150 pcs (one box contains 10 full trays)

Tape & Reel

SMD versions, SI, can be delivered in standard tape & reel package (designated by /C) on request, see fig. 7. For more information, please contact your local Ericsson sales office.

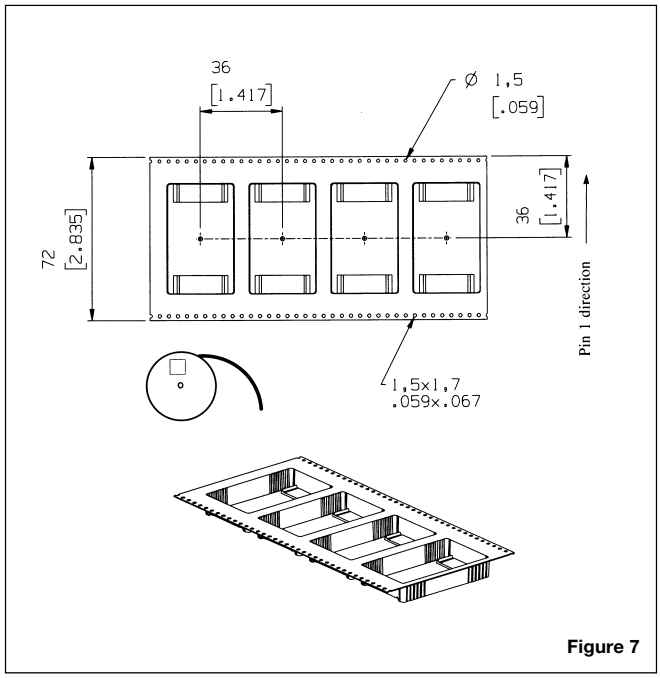


Figure 7

Specification

Tape material:	Conductive polystyrene (PS)
Tape width:	72 mm
Tape pitch:	36 mm
Max surface resistance:	$10^{5}\Omega/\square$
Tape color:	Black
Cover tape color:	Transparent
Reel diameter:	13"
Reel hub diameter:	7"
Reel capacity:	150 pcs
Full reel weight:	Typ. 3.7 kg
Min. order quantity:	300 pcs (one box contains two reels)

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Quality

Reliability

Meantime between failure (MTBF) is calculated to >4.9 million hours at full output power and a pin temperature of +55°C (T_A = +40°C), using the Ericsson failure rate data system. The Ericsson failure rate data system is based on field failure rates and is continously updated. The data corresponds to actual failure rates of components used in Information Technology and Telecom equipment in temperature controlled environments (T_A = –5… +65°C). The data is considered to have a confidence level of 90%. For more information see Design Note 002.

Quality Statement

The products are designed and manufactured in an industrial environment where quality systems and methods like ISO 9000, 6σ and SPC, are intensively in use to boost the continuous improvements strategy. Infant mortality or early failures in the products are screened out by a burn-in procedure and an ATE-based final test.
Conservative design rules, design reviews and product qualifications, plus the high competence of an engaged work force, contribute to the high quality of our products.

Warranty

Ericsson Microelectronics warrants to the original purchaser or end user that the products conform to this Data Sheet and are free from material and workmanship defects for a period of five (5) years from the date of manufacture, if the product is used within specified conditions and not opened. In case the product is discontinued, claims will be accepted up to three (3) years from the date of the discontinuation.
For additional details on this limited warranty please refer to Ericsson Microelectronics AB's "General Terms and Conditions of Sales", or individual contract documents.

Limitation of liability

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Product Program

V_I	V_O/I_O max	P_O max	Ordering No.*)	
	Output 1		Through-hole	SMD
24/48/60 V (max 75 Vdc)	3.3 V/1.5 A 5 V/1.2 A 7 V/0.86 A	5 W 6 W 6 W	PKF 5510 PI PKF 5611 PI PKF 5617 PI	PKF 5510 SI PKF 5611 SI PKF 5617 SI

*) See also Delivery Package Information

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Data Sheet

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